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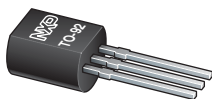
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BT1306-400D/600D

Logic level triac

Rev. 2 — 14 September 2011

Product data sheet

1. Product profile

1.1 General description

Logic level sensitive gate triac intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

1.2 Features and benefits

- Sensitive gate in all four quadrants
- Low cost package.

1.3 Applications

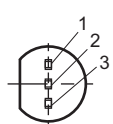
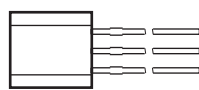

- General purpose bidirectional switching
- Solid state relays
- Phase control applications
- Low power AC fan speed controllers.

1.4 Quick reference data

- $V_{\text{DRM}} \leq 600 \text{ V}$ (BT1306-600D)
- $I_{\text{TSM}} \leq 8 \text{ A}$
- $V_{\text{DRM}} \leq 400 \text{ V}$ (BT1306-400D)
- $I_{\text{T(RMS)}} \leq 0.6 \text{ A}$.

2. Pinning information

Table 1. Pinning - SOT54 (TO-92), simplified outline and symbol

Pin	Description	Simplified outline	Symbol
1	main terminal 2	  <i>msb033</i>	 <i>mbi305</i>
2	gate		
3	main terminal 1		
		SOT54 (TO-92)	



3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BT1306-600D	TO-92	Plastic single-ended leaded (through hole) package; 3 leads	SOT54
BT1306-400D	TO-92	Plastic single-ended leaded (through hole) package; 3 leads	SOT54

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage				
	BT1306-600D	$25\text{ }^{\circ}\text{C} \leq T_j \leq 125\text{ }^{\circ}\text{C}$	-	600	V
	BT1306-400D		-	400	V
$I_{\text{T(RMS)}}$	on-state current (RMS value)	full sine wave; $T_{\text{lead}} \leq 65\text{ }^{\circ}\text{C}$; Figure 1 and 2	-	0.6	A
I_{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge; Figure 3 and 4			
		$t = 20\text{ ms}$	-	8	A
		$t = 16.7\text{ ms}$	-	8.8	A
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	0.32	A ² s
di_{T}/dt	repetitive rate of rise of on-state current after triggering	$I_{\text{TM}} = 1\text{ A}$; $I_{\text{G}} = 0.2\text{ A}$; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$			
		T2+ G+	-	50	A/ μs
		T2+ G-	-	50	A/ μs
		T2- G-	-	50	A/ μs
		T2- G+	-	10	A/ μs
I_{GM}	gate current (peak value)	$t = 2\text{ }\mu\text{s max}$	-	1	A
V_{GM}	gate voltage (peak value)		-	5	V
P_{GM}	gate power (peak value)		-	5	W
$P_{\text{G(AV)}}$	average gate power	$t = 2\text{ }\mu\text{s max}$; $T_{\text{case}} \leq 80\text{ }^{\circ}\text{C}$	-	0.1	W
T_{stg}	storage temperature		-40	+150	$^{\circ}\text{C}$
T_j	junction temperature		-40	+125	$^{\circ}\text{C}$

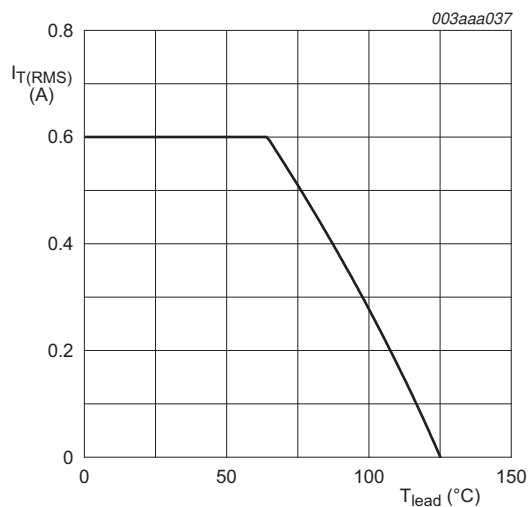
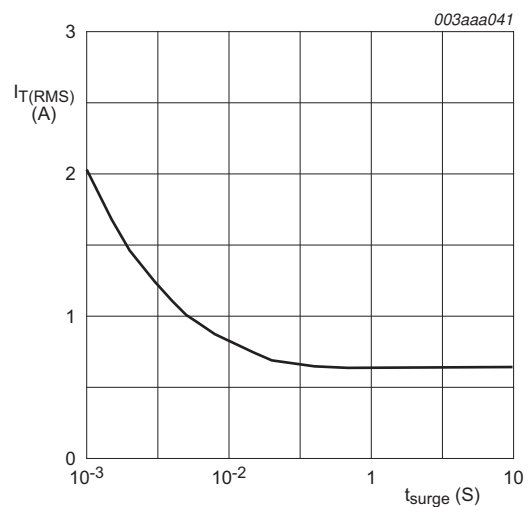
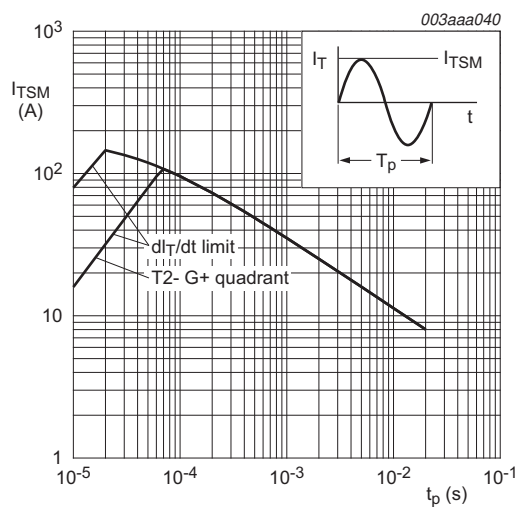


Fig 1. Maximum permissible on-state current (RMS value) as a function of lead temperature.



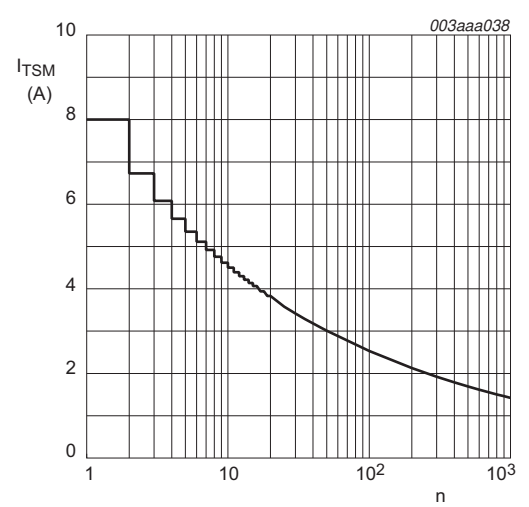
$f = 50$ Hz
 $T_{lead} \leq 65$ $^{\circ}C$

Fig 2. Maximum permissible repetitive on-state current (RMS value) as a function of surge duration for sinusoidal currents.



$t_p \leq 20$ ms
initial $T_j \leq 25$ $^{\circ}C$

Fig 3. Maximum permissible non-repetitive peak on-state current as a function of pulse width for sinusoidal currents.



n = number of cycles
 $f = 50$ Hz
initial $T_j \leq 25$ $^{\circ}C$

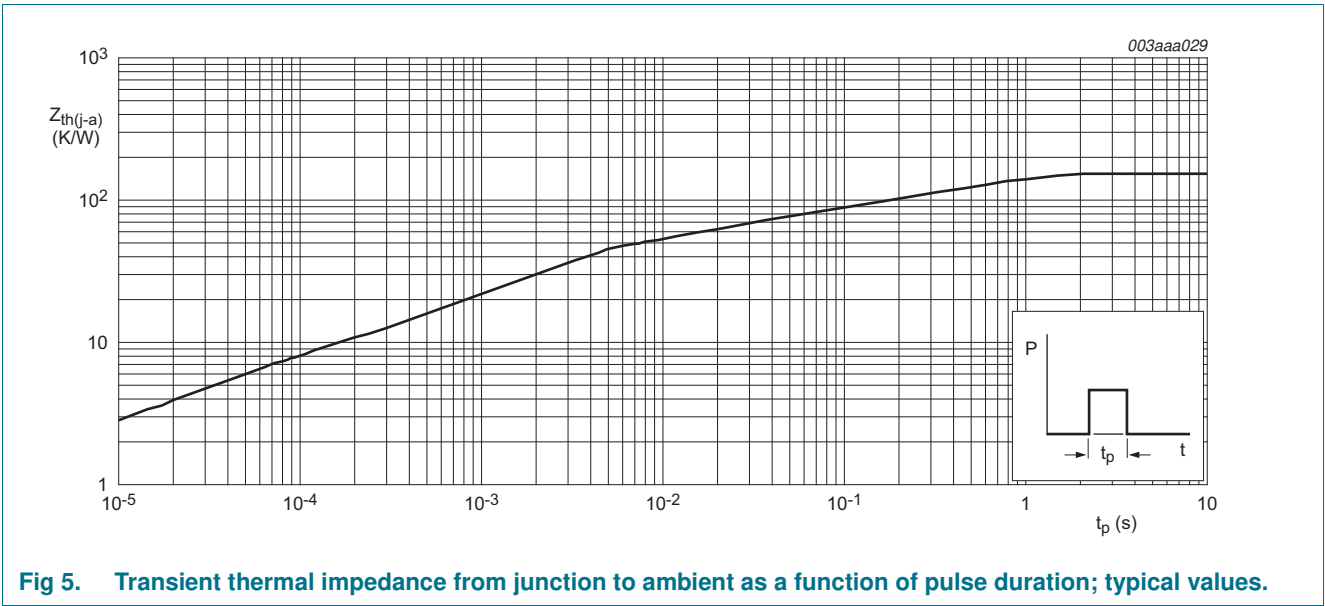
Fig 4. Maximum permissible non-repetitive peak on-state current as a function of number of cycles for sinusoidal currents; typical values.

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle	-	-	60	K/W
		half cycle			80	
$R_{th(j-a)}$	thermal resistance from junction to ambient	mounted on a printed-circuit board; lead length = 4 mm; Figure 5	-	150	-	K/W

5.1 Transient thermal impedance

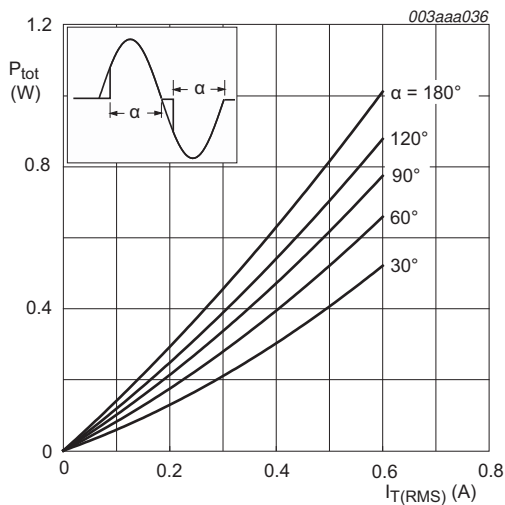


6. Characteristics

Table 5. Characteristics

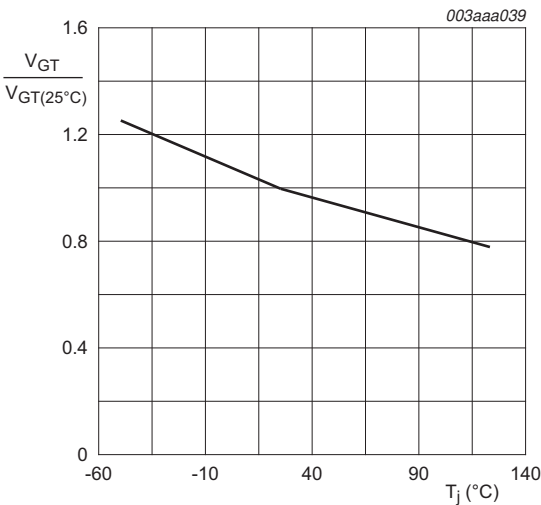
$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
I_{GT}	gate trigger current	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 8				
		T2+ G+	-	1	5	mA
		T2+ G-	-	2	5	mA
		T2- G-	-	2	5	mA
I_L	latching current	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 9				
		T2+ G+	-	1	10	mA
		T2+ G-	-	5	10	mA
		T2- G-	-	1	10	mA
I_H	holding current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$; Figure 10	-	1	10	mA
		$I_T = 0.85\text{ A}$; Figure 11	-	1.4	1.9	V
		$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 7	-	0.9	2	V
		$V_D = V_{DRM}$; $I_T = 0.1\text{ A}$; $T_j = 110\text{ }^{\circ}\text{C}$	0.1	0.7	-	V
I_D	off-state leakage current	$V_D = V_{DRM(max)}$; $T_j = 110\text{ }^{\circ}\text{C}$	-	3	100	μA
Dynamic characteristics						
dV_D/dt	critical rate of rise of off-state voltage	$V_D = 67\%$ of $V_{DM(max)}$; $T_{case} = 110\text{ }^{\circ}\text{C}$; exponential waveform; gate open circuit; Figure 12	30	45	-	$\text{V}/\mu\text{s}$
dV_{com}/dt	critical rate of rise of commutation voltage	$V_D = \text{rated } V_{DM}$; $T_{case} = 50\text{ }^{\circ}\text{C}$; $I_{TM} = 0.84\text{ A}$; commutating $dI/dt = 0.3\text{ A/ms}$	-	5	-	$\text{V}/\mu\text{s}$
t_{gt}	gate controlled turn-on time	$I_{TM} = 1.0\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 25\text{ mA}$; $dI_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	μs



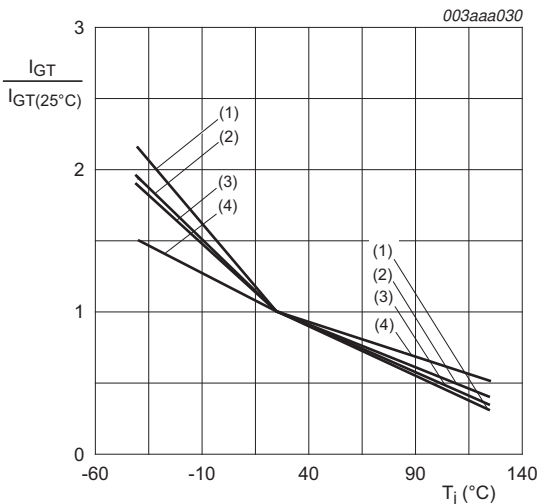
α = conduction angle

Fig 6. On-state dissipation as a function of on-state current (RMS value); maximum values.



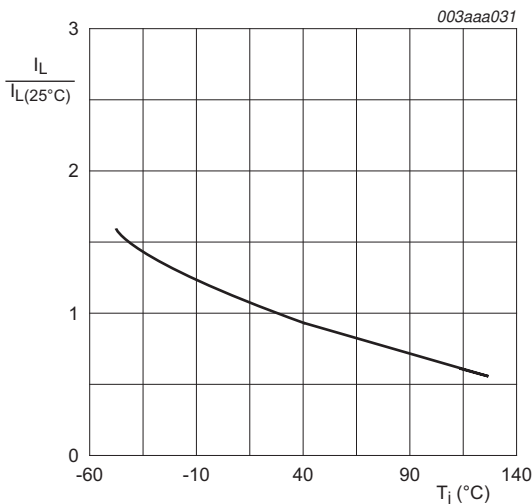
$$a = \frac{V_{GT(T_j)}}{V_{GT(25^\circ C)}}$$

Fig 7. Normalized gate trigger voltage as a function of junction temperature; typical values.



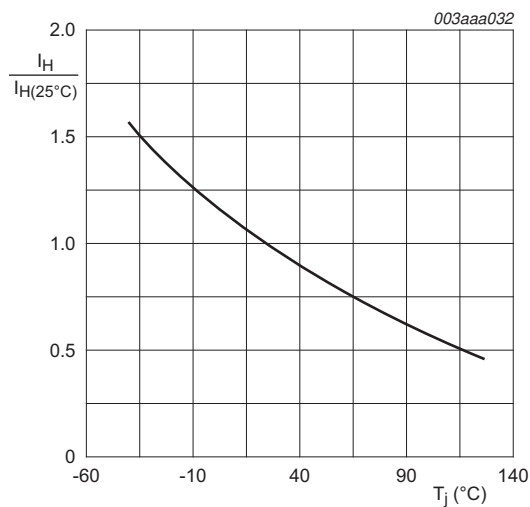
$$a = \frac{I_{GT(T_j)}}{I_{GT(25^\circ C)}}$$

Fig 8. Normalized gate trigger current as a function of junction temperature; typical values.



$$a = \frac{I_{L(T_j)}}{I_{L(25^\circ C)}}$$

Fig 9. Normalized latching current as a function of junction temperature; typical values.



$$a = \frac{I_{H(T_j)}}{I_{H(25^\circ\text{C})}}$$

Fig 10. Normalized holding current as a function of junction temperature; typical values.

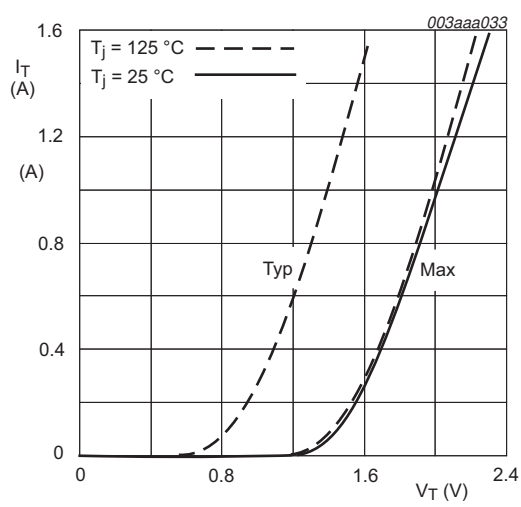


Fig 11. On-state current as a function of on-state voltage; typical and maximum values.

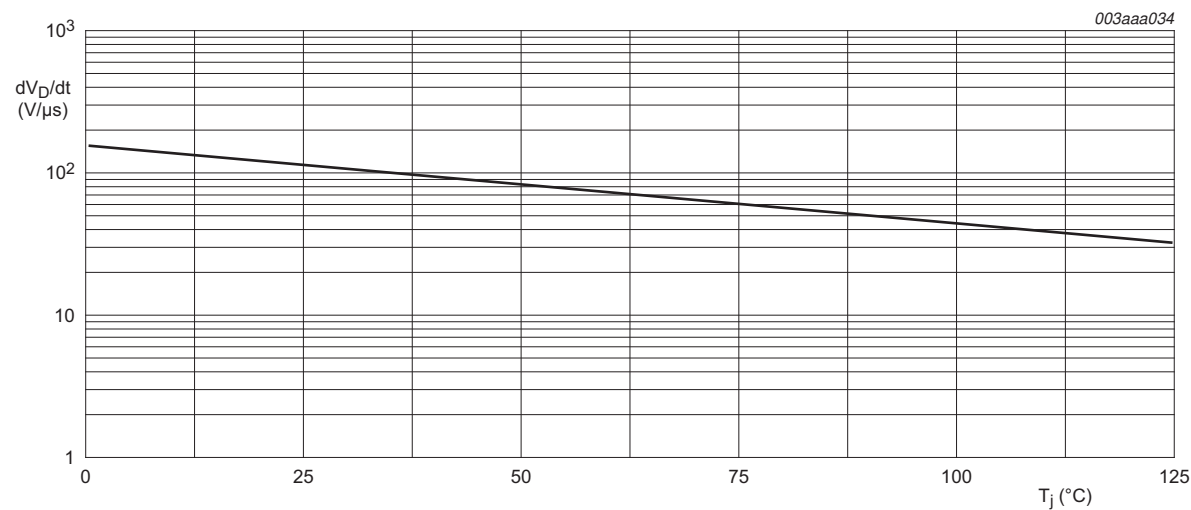


Fig 12. Critical rate of rise of off-state voltage as a function of junction temperature; typical values.

7. Package outline

Plastic single-ended leaded (through hole) package; 3 leadsSOT54

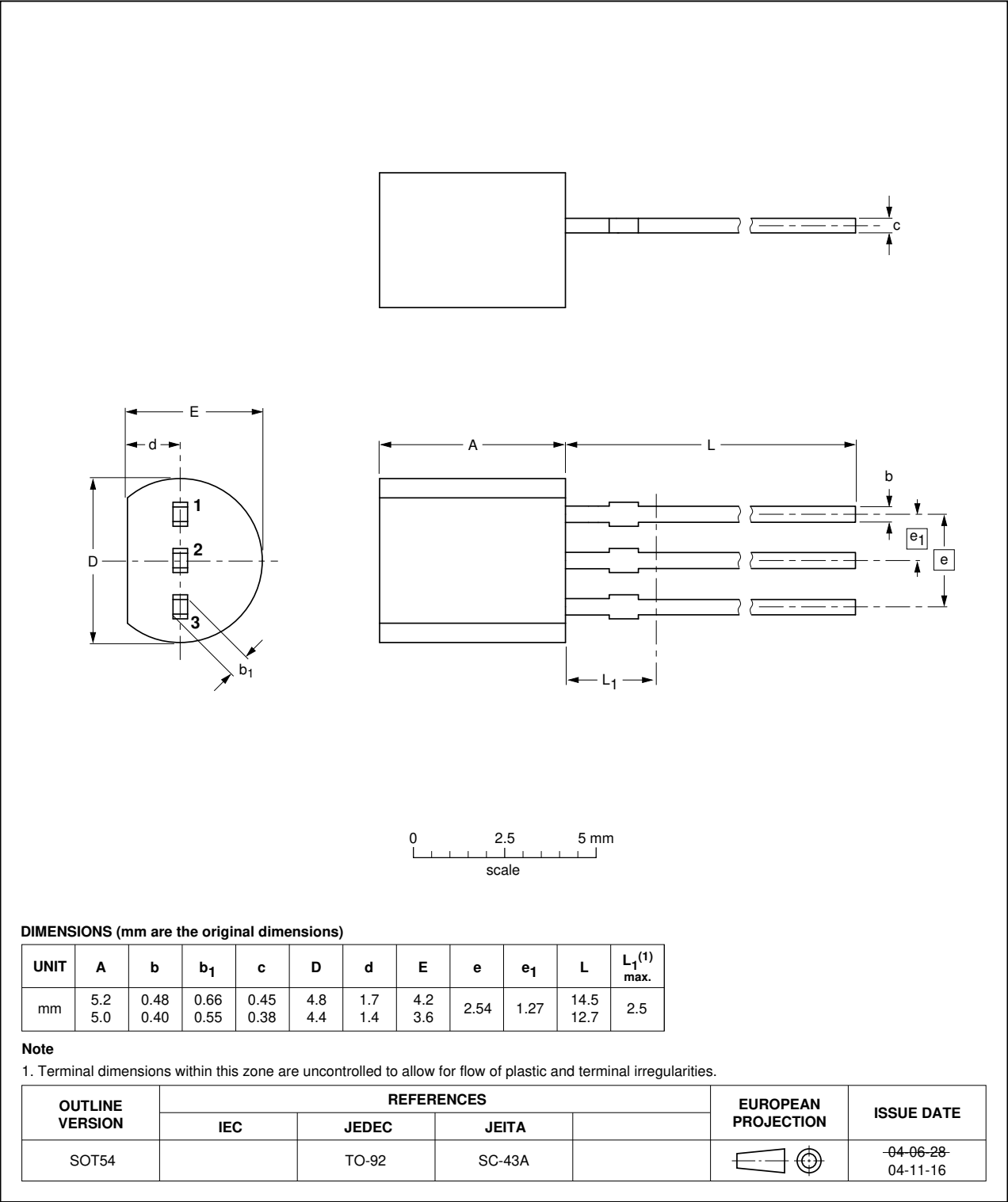


Fig 13. SOT54 (TO-92).

8. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BT1306_XXXD_SER v.2	20110914	Product data sheet	-	BT1306_XXXD_SER v.1 (9397 750 12593)
Modifications:	<ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Package outline drawings have been updated to the latest version.			
BT1306_XXXD_SER v.1 (9397 750 12593)	20040219	Product data	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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11. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	1
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	4
5.1	Transient thermal impedance	4
6	Characteristics	5
7	Package outline	8
8	Revision history	9
9	Legal information	10
9.1	Data sheet status	10
9.2	Definitions	10
9.3	Disclaimers	10
9.4	Trademarks	11
10	Contact information	11
11	Contents	12

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Date of release: 14 September 2011

Document identifier: BT1306_XXxD_SER